## 54ACT11828, 74ACT11828 10-BIT BUFFERS/BUS DRIVERS WITH 3-STATE OUTPUTS

SCAS092 - D3387, APRIL 1993

- Inputs Are TTL-Voltage Compatible
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Flow-Through Architecture to Optimize PCB Layout
- Center-Pin V<sub>CC</sub> and GND Configurations to Minimize High-Speed Switching Noise
- *EPIC*<sup>™</sup> (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages, Ceramic Chip Carriers, and Standard Ceramic 300-mil DIPs

#### description

These 10-bit buffers/bus drivers provide highperformance bus interface for wide data paths or buses carrying parity.

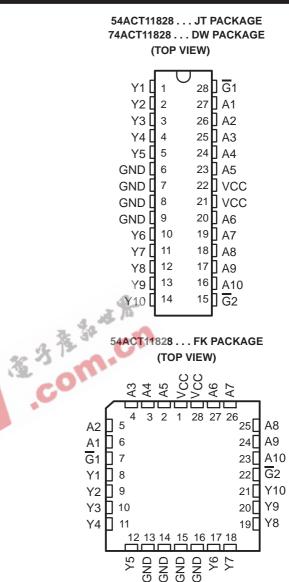
The 3-state control gate is a 2-input NOR such that if either  $\overline{G}1$  or  $\overline{G}2$  is high, all ten outputs are in the high-impedance state.

The 'ACT11828 provides inverted data.

The 54ACT11828 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The 74ACT11828 is characterized for operation from  $-40^{\circ}$ C to 85°C.

FUNCTION	TABLE

	NPUTS	OUTPUT	
G1	G2	Α	Y
L	L	Н	L
L	L	L	н
Х	Н	Х	Z
н	Х	Х	Z

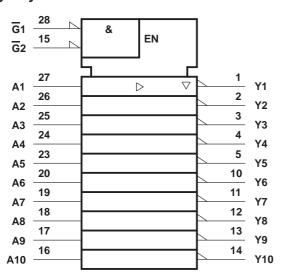


EPIC is a trademark of Texas Instruments Incorporated.



### 54ACT11828, 74ACT11828 10-BIT BUFFERS/BUS DRIVERS WITH 3-STATE OUTPUTS SCAS092 – D3387, APRIL 1993

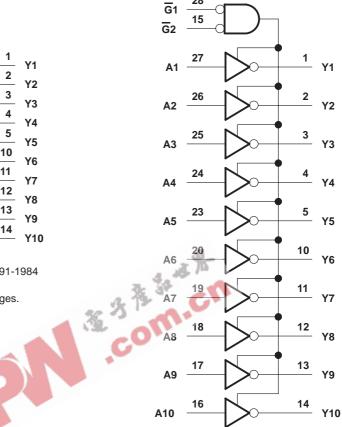
### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the DW, JT, and NT packages.





### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	$\dots \dots \dots \dots -0.5$ V to V <sub>CC</sub> + 0.5 V
Output voltage range, V <sub>O</sub> (see Note 1)	$-0.5$ V to V <sub>CC</sub> + 0.5 V
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ )	± 20 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ or $V_O > V_{CC}$ )	± 50 mA
Continuous output current, $I_O (V_O = 0 \text{ to } V_{CC})$	± 50 mA
Continuous current through V <sub>CC</sub> or GND	± 250 mA
Storage temperature range	–65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



### recommended operating conditions

		54ACT11828		74ACT11828		UNIT
		MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage	4.5	5.5	4.5	5.5	V
VIH	High-level input voltage	2		2		V
VIL	Low-level input voltage		0.8		0.8	V
VI	Input voltage	0	VCC	0	VCC	V
VO	Output voltage	0	VCC	0	VCC	V
ЮН	High-level output current		-24		-24	mA
IOL	Low-level output current		24		24	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	0	10	ns/V
TA	Operating free-air temperature	-55	125	- 40	85	°C

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T <sub>A</sub> = 25°C 🚮	54ACT11828	74ACT11828	UNIT
			MIN TYP MAX	MIN MAX	MIN MAX	UNIT
	I <sub>OH</sub> = - 50 μA	4.5 V	4.4 🌺 😵 👝	4.4	4.4	V
		5.5 V	5.4	5.4	5.4	
Vou	I <sub>OH</sub> = – 24 mA	4.5 V	3.94	3.7	3.8	
VOH	10H = - 24 IIIA	5.5 V	4.94	4.7	4.8	v
	I <sub>OH</sub> = - 50 mA <sup>†</sup>	5.5 V		3.85		
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V			3.85	
	I <sub>OL</sub> = 50 μA	4.5 V	0.1	0.1	0.1	
		5.5 V	0.1	0.1	0.1	
VOL	I <sub>OL</sub> = 24 mA	4.5 V	0.36	0.5	0.44	
VOL		5.5 V	0.36	0.5	0.44	
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V		1.65		
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V			1.65	
IOZ	$V_{O} = V_{CC}$ or GND	5.5 V	± 0.5	± 10	±5	μΑ
l	$V_{I} = V_{CC}$ or GND	5.5 V	± 0.1	± 1	±1	μΑ
ICC	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V	8	160	80	μΑ
$\Delta I_{CC}^{\ddagger}$	One input at 3.4 V, Other inputs at GND or V <sub>CC</sub>	5.5 V	0.9	1	1	mA
Ci	$V_I = V_{CC}$ or GND	5 V	4.5			pF
Co	$V_{I} = V_{CC}$ or GND	5 V	12			pF

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

<sup>±</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V to V<sub>CC</sub>.



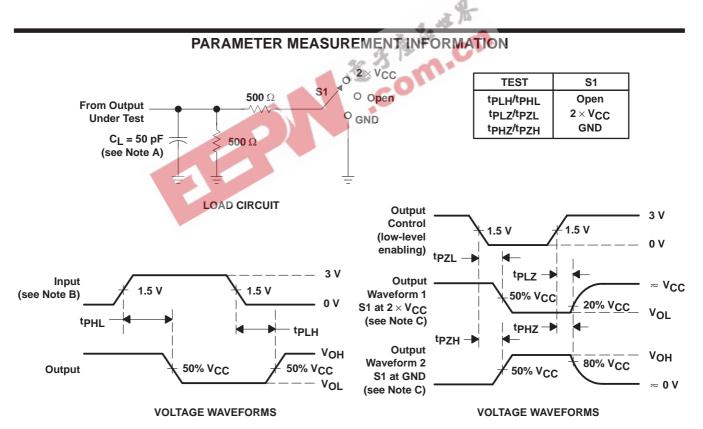
### 54ACT11828, 74ACT11828 10-BIT BUFFERS/BUS DRIVERS WITH 3-STATE OUTPUTS SCAS092 – D3387, APRIL 1993

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

PARAMETER	FROM TO (INPUT) (OUTPU	то	T <sub>A</sub> = 25°C		54ACT11828		74ACT11828		UNIT	
PARAMETER		(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
<sup>t</sup> PLH	A or B	Y	1.9	5.6	8.3	1.9	10.9	1.9	10.2	ns
<sup>t</sup> PHL			5.2	8	10.3	5.2	12.4	5.2	11.7	
<sup>t</sup> PZH	G1 or G2	or G2 Y	2.9	7	9.9	2.9	13	2.9	12.1	20
<sup>t</sup> PZL			3.4	8.3	11.4	3.4	15.8	3.4	14.7	ns
<sup>t</sup> PHZ	$\overline{G}1 \text{ or } \overline{G}2$	<u> </u>	6	9	11.3	6	12.9	6	12.3	20
<sup>t</sup> PLZ		ſ	5.9	8.5	10.9	5.9	12.3	5.9	11.7	ns

### operating characteristics, $V_{CC} = 5 V$ , $T_A = 25^{\circ}C$

PARAMETER		TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance	Outputs enabled	C <sub>I</sub> = 50 pF. f = 1 MHz	37	nΕ
	Outputs disabled	$C_L = 50 \text{ pF}, \text{ f} = 1 \text{ MHz}$	11	ρг



NOTES: A. CL includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics:  $PRR \le 10 \text{ MHz}$ ,  $Z_0 = 50 \Omega$ ,  $t_r = 3 \text{ ns}$ ,  $t_f = 3 \text{ ns}$ .
- C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- D. The outputs are measured one at a time with one input transition per measurement.

### Figure 1. Load Circuit and Voltage Waveforms



#### **IMPORTANT NOTICE**

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. Tt's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.



Copyright © 1998, Texas Instruments Incorporated